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MSME3103AM5G

Product specification

GENERAL DESCRIPTION

The MSME3103AM5G is a compact 5V Buck Converter which can deliver 1A output current.

MSME3103AM5G employs a proprietary control loop to achieve a fast transient load response. It keeps high converting efficiency in both light load and heavy load.

MSME3103AM5G is equipped with all kinds of protection, such as input over voltage protection, output short circuit protection, over current protection and over temperature protection.

MSME3103AM5G is consists of internal power tree generator, bandgap voltage reference module, under-voltage-lockout (UVLO) module, error amplifier, protection circuitry, driver block, current sensing block and two power MOSFETs.

MSME3103AM5G is housed in a SOT23-5 package.

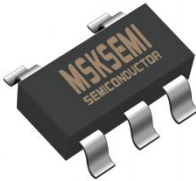

FEATURES

- Input operation range: 2.2– 5.5V
- Input over voltage protection at 6V
- 30uA quiescent current in operation
- Output current up to 1A
- Efficiency up to 95%
- OCP, SCP and OTP protection
- SOT23-5 package

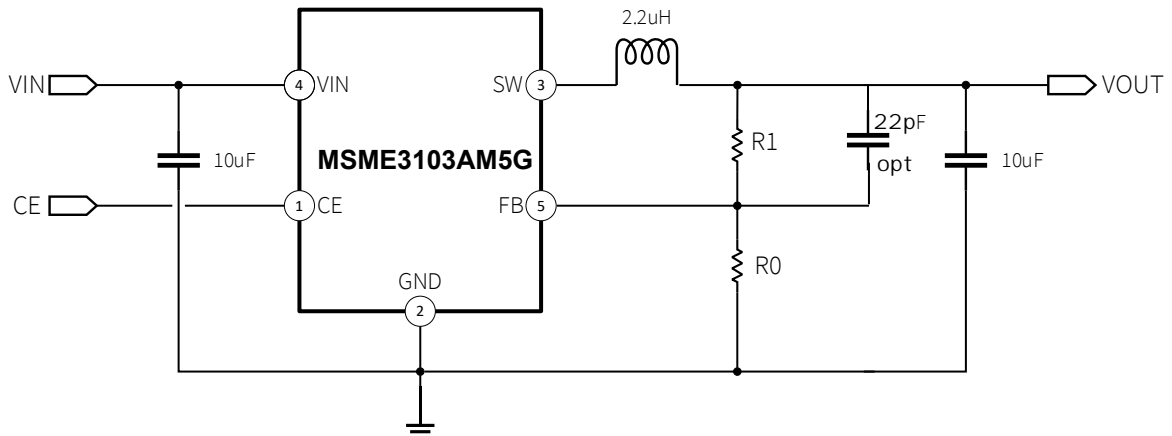
Applications

- Set-top Box
- Solid State Drive
- WIFI and Network Devices
- Security surveillance system
- Toys
- TV
- All other electronic devices

Reference News

Type No	SOT-23-5	MARKING
MSME3103AM5G		

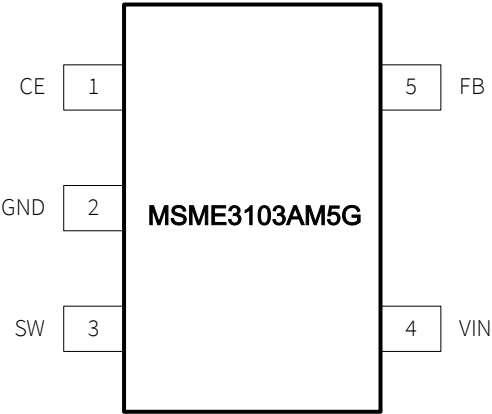
Typical Application Circuit



ORDER INFORMATION

P/N	PKG	QTY
MSME3103AM5G	SOT-23-5	3000

Pin Assignment



The package of MSME3103AM5G is SOT-23-5 , with pin assignment shown in following table:

Pin No	Name	Description
1	CE	Chip enable pin, pull high to turn on the chip
2	GND	Ground
3	SW	The switching node, connecting a 2.2uH inductor to this node
4	VIN	The input power node, connecting a 10uF capacitor to ground.
5	FB	Feedback node, with Vfb at 0.6V

Absolute Maximum Ratings

$V_{IN}^{(1)}$	-0.3V to 6V
$V_{OUT}^{(1)}$	-0.3V to 5.5V
Continuous Power Dissipation ($T_A = 25^{\circ}\text{C}$) ⁽²⁾	
SOT-23-5	0.4W
Junction Temperature.....	-40°C to 125°C
Lead Temperature.....	260°C
Storage Temperature.....	-65°C to +150°C
Thermal Resistance ⁽³⁾	θ_{JA} θ_{JC}
SOT-23-5.....	170°C /W.....75°C /W

Notes:

- (1) Exceeding these ratings may damage the device.
- (2) The maximum allowable power dissipation is a function of the maximum junction temperature $T_{J(MAX)}$, the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_D(MAX) = (T_{J(MAX)} - T_A) / \theta_{JA}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- (3) Measured on JESD51-7, 4-layer PCB.

Electrical Characteristics

All typical values are at $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input voltage range, V_{IN}		2.2		5.5	V
Input over voltage protection		5.8	6	6.5	V
Quiescent current, I_Q	$V_{IN} = 5V$	20	30	60	μA
Shutdown current, I_{OFF}	$V_{IN} = 5V, V_{CE} = 0$		0.1	2	μA
Input voltage UVLO	Rising		2.55	2.65	V
	Falling	2.25	2.37		V
Feedback voltage	$V_{IN} = 5V$	0.588	0.6	0.612	V
Output current Limit	$V_{IN} = 5V, V_{OUT} = 3.3V$	1	1.2		A
Line regulation	$V_{IN} = 3 \text{ to } 5V$		0.2		%/V
Load regulation	$I_{OUT} = 0.1 - 1A$		0.1	2	%/A
Switching frequency	$V_{IN} = 5V$	1	1.5	2	MHz
ON resistance PMOS	$V_{IN} = 5V$		0.38		Ω
ON resistance NMOS	$V_{IN} = 5V$		0.25		Ω
CE input threshold ON	$V_{IN} = 5V$		0.9	1.1	V
CE input threshold OFF	$V_{IN} = 5V$	0.4	0.7		V
CE input pull down resistor			750		K Ω
Output discharge resistor, R_{pd}	$V_{IN} = 5V$		600		Ω
Over temperature protection			150		$^{\circ}\text{C}$
OTP hysteresis			40		$^{\circ}\text{C}$

Application Information

Output Voltage Setting

MSME3103AM5G's feedback voltage is set at 0.6V, and it requires a resistor from FB node to ground, named R0, which is suggested to be less than 120K. Assuming the resistor between output node and FVB node is R1, the output voltage of DC-DC converting system is given by

$$V_{out} = \frac{0.6V}{R_0} \times (R_1 + R_0)$$

Capacitor Selection

MSME3103AM5G requires one minimal 10uF MLCC capacitor at VIN node and one 10uF MLCC capacitor at VOUT node, however, it is always recommended to have two 10uF MLCC capacitors placed in parallel both at VIN and VOUT node to minimize the noise and withstand the current surge. It is also essential to place both input capacitors and output capacitors as close to MSME3103AM5G's VIN pin and VOUT pin as possible. A PCB layout example is shown at PCB layout recommendation section.

Inductor Selection

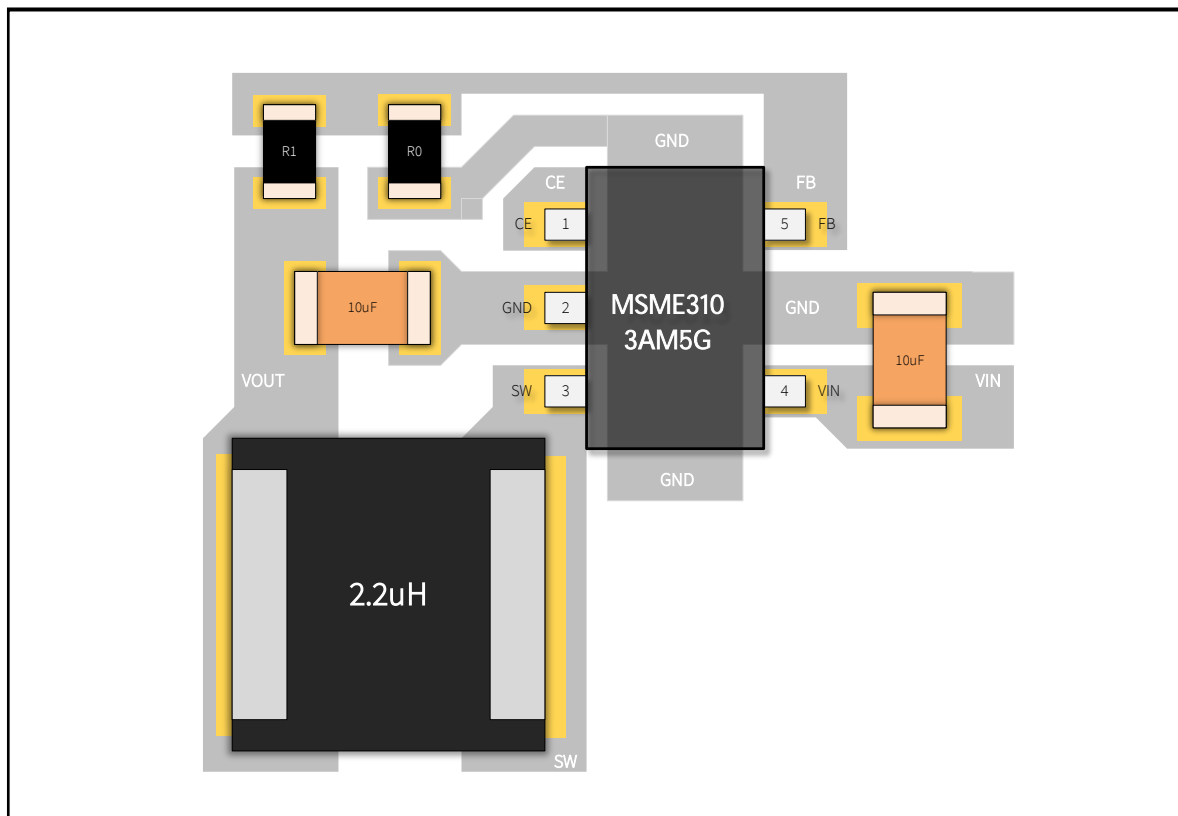
MSME3103AM5G works at a 1.5MHz oscillating frequency which helps to have a small voltage ripple at output. And 2.2uH inductor is found to be the most suitable value while meeting requirements on small output voltage ripple as well as a high-power conversion efficiency.

Thermal Considerations

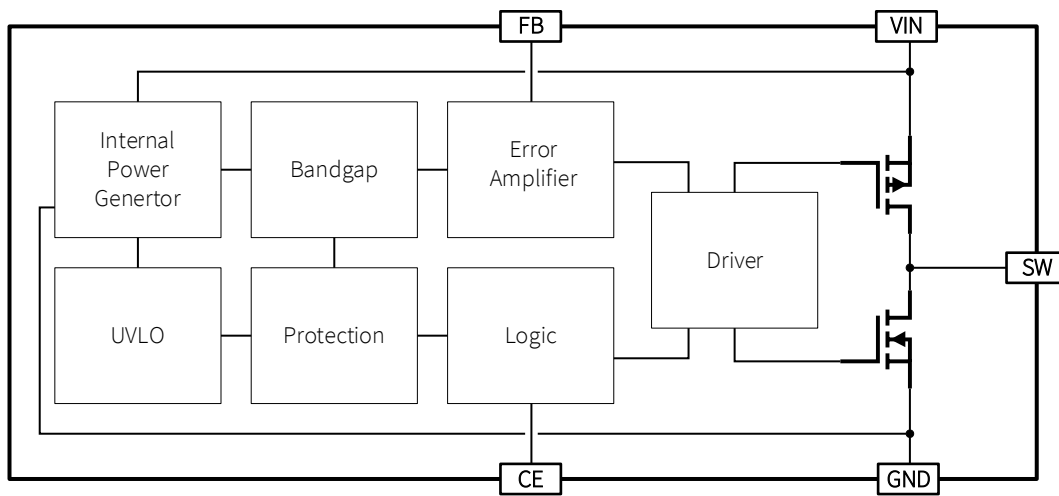
Though MSME3103AM5G is a high efficiency DC/DC converter, there will always be some power lost during conversion, most of which becomes heat to make junction temperature higher. PCB design to ensure a good heat dissipation is important. Because the heat dissipation of the SOT-23-5 package is conducted through the pin No. 2, which is GND node of MSME3103AM5G, please make sure the ground plane of PCB is big enough to carry away the heat generated in the chip.

PCB Layout

An illustration of PCB layout recommendation with key elements is laid out as following. Please follow this PCB instruction to place the key peripheral devices such as input capacitors, output capacitors and inductor. And star-like connection for ground node is essential. And keeping power loop area as small as possible will improve the EMI performance.

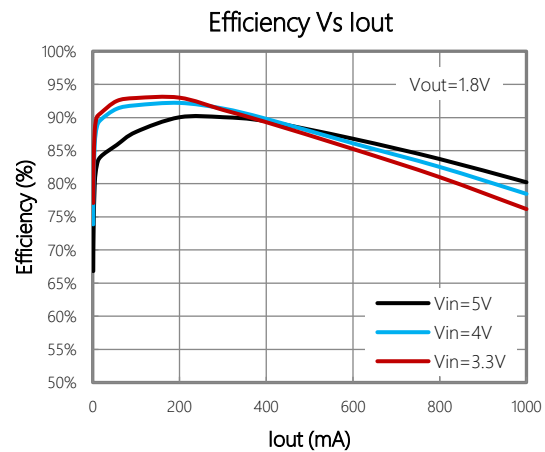
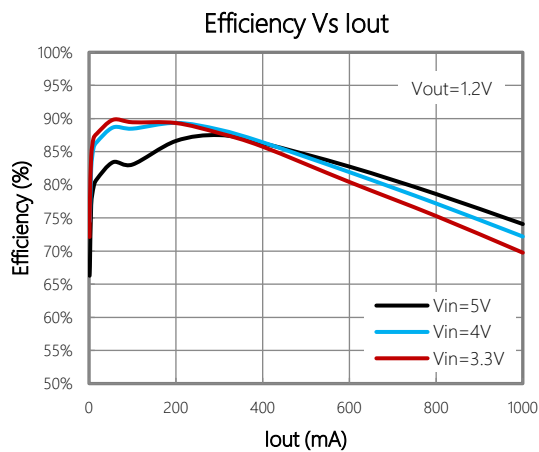


Block Diagram



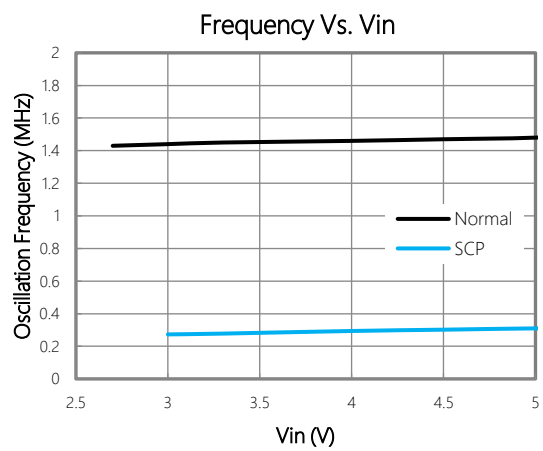
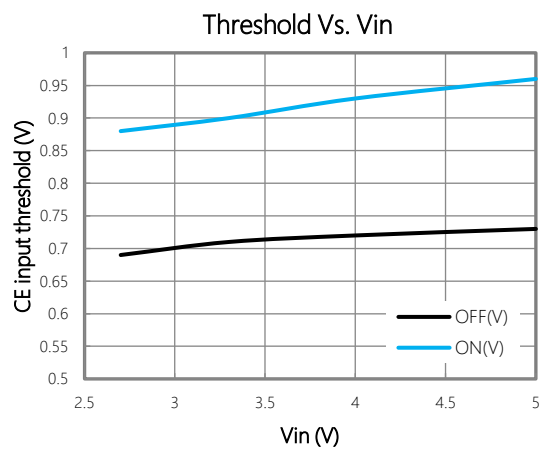
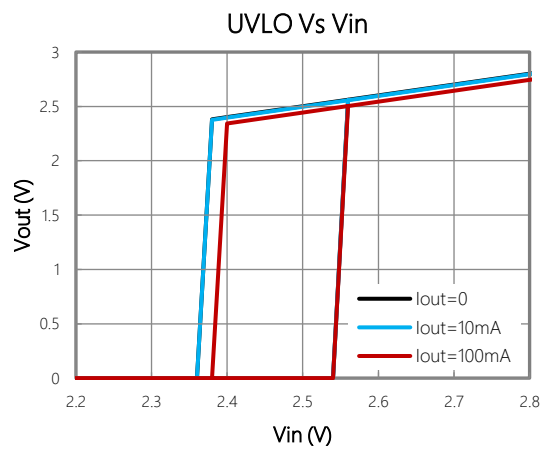
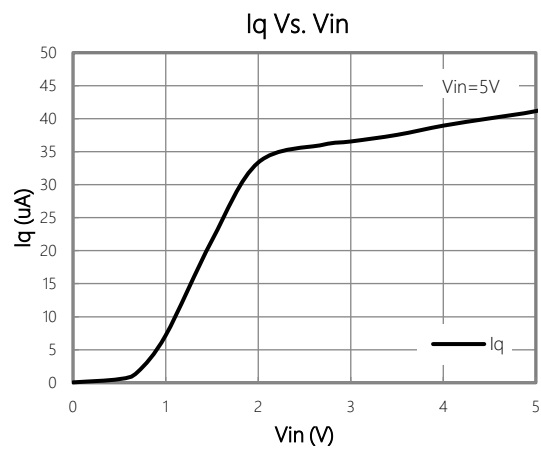
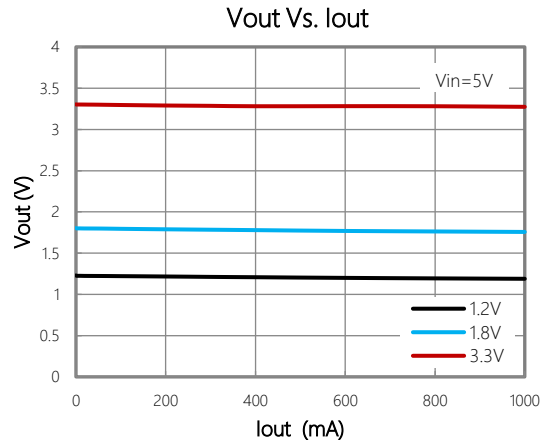
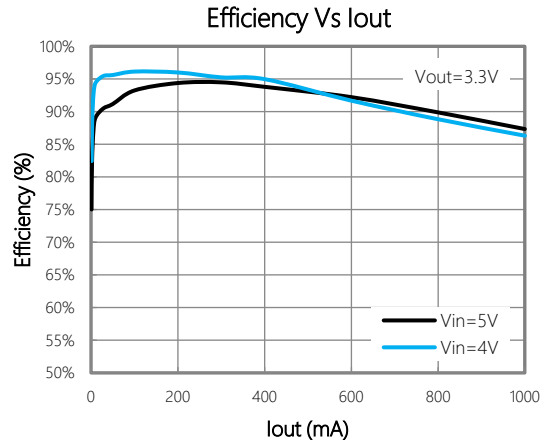
Typical Characteristics

$C_{IN}=C_{OUT}=10\mu F$, $T_A = 25^\circ C$, unless otherwise specified



Typical Characteristics (cont')

$C_{IN}=C_{OUT}=10\mu F$, $T_A = 25^\circ C$, unless otherwise specified

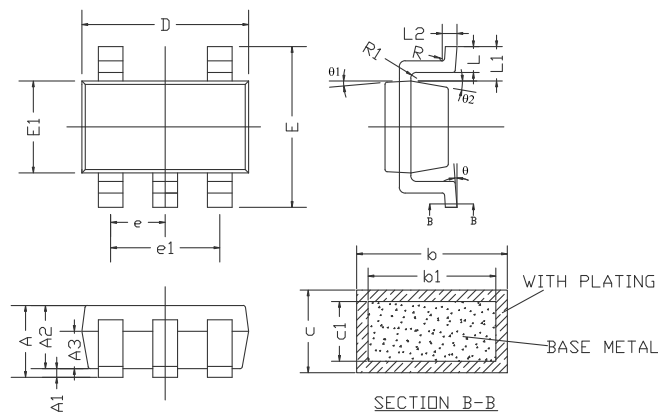


Package Outline

Package SOT23-5

Devices per reel

Package dimension (mm):



Symbol	MIN	NORM	MAX
A	-	-	1.25
A1	0.00	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59 REF		
L2	0.25 BSC		
R	0.05	-	-
R1	0.05	-	0.20
Θ	0°	-	8°
Θ1	3°	5°	7°
Θ2	6°	-	14°

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